



20V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage 20 V Current 1.2 A

Features

- RDS(ON), VGS@4.5V, ID@1.2A<380mΩ
- RDS(ON), VGS@2.5V, ID@0.7A<680mΩ
- RDS(ON) , VGS@1.8V, ID@0.2A<1100mΩ(typ.)
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

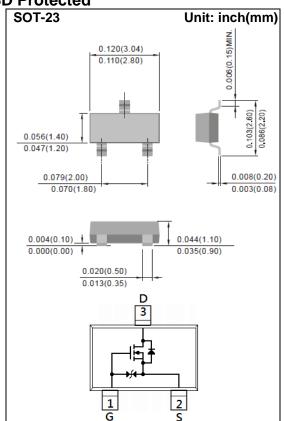
Mechanical Data

• Case: SOT-23 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A36



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|--|----------------------|-----------------|-------------|-------|
| Drain-Source Voltage | | V_{DS} | 20 | V |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 12 | V |
| Continuous Drain Current | | I _D | 1.2 | Α |
| Pulsed Drain Current (Note 4) | | I _{DM} | 4.8 | Α |
| Power Dissipation | T _a =25°C | P_{D} | 1.25 | W |
| | Derate above 25°C | | 10 | mW/°C |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | °C |
| Typical Thermal resistance | | | | |
| - Junction to Ambient (Note 3) | | $R_{\theta JA}$ | 100 | °C/W |





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---------------------|--|------|------------|-------------|-------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 20 | - | - | V | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250uA$ | 0.4 | 0.65 | 1.0 | V | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =4.5V, I _D =1.2A | - | 310 | 380 | mΩ | |
| | | V _{GS} =2.5V, I _D =0.7A | - | 440 | 680 | | |
| | | V _{GS} =1.8V, I _D =0.2A | - | 700 | - | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =16V, V _{GS} =0V | - | 0.02 | 1 | uA | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 10V, V _{DS} =0V | - | <u>+</u> 2 | <u>+</u> 10 | uA | |
| Dynamic | | | | | | | |
| Total Gate Charge | Q_g | V _{DS} =10V, I _D =1.2A, V _{GS} =4.5V ^(Note 1,2) | - | 0.9 | - | nC | |
| Gate-Source Charge | Q_gs | | - | 0.2 | - | | |
| Gate-Drain Charge | Q_gd | | - | 0.2 | - | | |
| Input Capacitance | Ciss | V _{DS} =10V, V _{GS} =0V, f=1.0MHZ | - | 39 | - | pF | |
| Output Capacitance | Coss | | - | 15 | - | | |
| Reverse Transfer Capacitance | Crss | I=I.UIVIMZ | - | 9 | - | | |
| Switching | | | | | | | |
| Turn-On Delay Time | td _(on) | \/ 40\/ L 40A | - | 2.2 | - | | |
| Turn-On Rise Time | tr | V_{DD} =10V, I_{D} =1.2A, V_{GS} =4.5V, R_{G} =6 $\Omega^{(Note 1,2)}$ | - | 22 | - | ns | |
| Turn-Off Delay Time | td _(off) | | - | 9 | - | | |
| Turn-Off Fall Time | tf | | - | 20 | - | | |
| Drain-Source Diode | | | | | | | |
| Maximum Continuous Drain-Source | 1 | | | | 1.0 | Α | |
| Diode Forward Current | I _S | | _ | - | 1.0 | A | |
| Diode Forward Voltage | V_{SD} | I _S =1.0A, V _{GS} =0V | - | 0.93 | 1.3 | V | |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.





TYPICAL CHARACTERISTIC CURVES

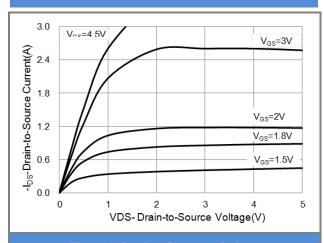


Fig.1 On-Region Characteristics

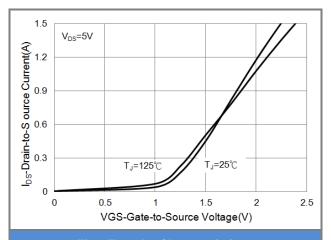


Fig.2 Transfer Characteristics

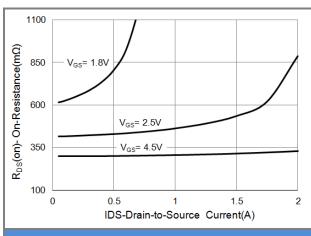


Fig.3 On-Resistance vs. Drain Current

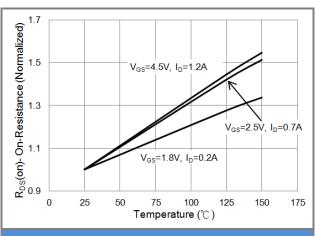
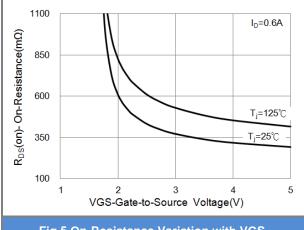
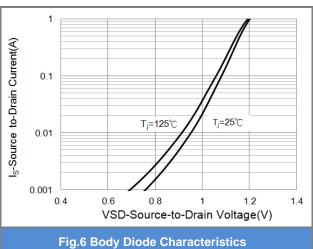


Fig.4 On-Resistance vs. Junction temperature











TYPICAL CHARACTERISTIC CURVES

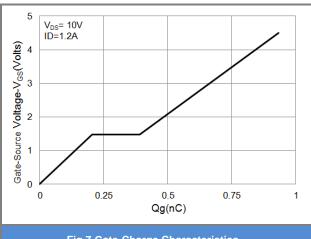


Fig.7 Gate-Charge Characteristics

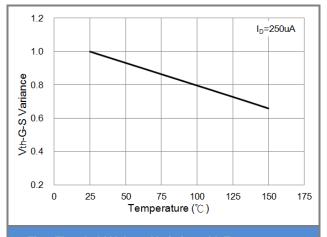


Fig.8 Threshold Voltage Variation with Temperature.

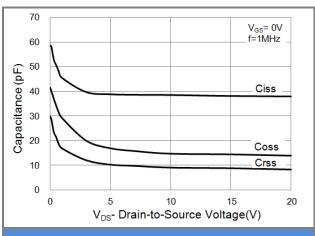


Fig.9 Threshold Voltage Variation with Temperature.

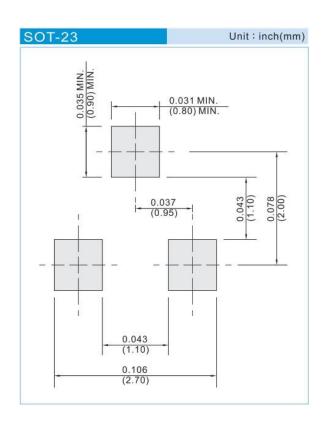




PART NO PACKING CODE VERSION

| PART NO PACKING CODE | Package Type | Packing type | Marking | Version |
|----------------------|--------------|--------------------|---------|--------------|
| PJA3436_R1_00001 | SOT-23 | 3K pcs / 7" reel | A36 | Halogen free |
| PJA3436_R2_00001 | SOT-23 | 12K pcs / 13" reel | A36 | Halogen free |

MOUNTING PAD LAYOUT







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